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"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	168MHz
Connectivity	CANbus, I²C, SPI, UART/USART
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	48
Program Memory Size	256KB (256K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	32K x 8
Voltage - Supply (Vcc/Vdd)	1.71V ~ 3.6V
Data Converters	A/D 29x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mkv42f256vlh16

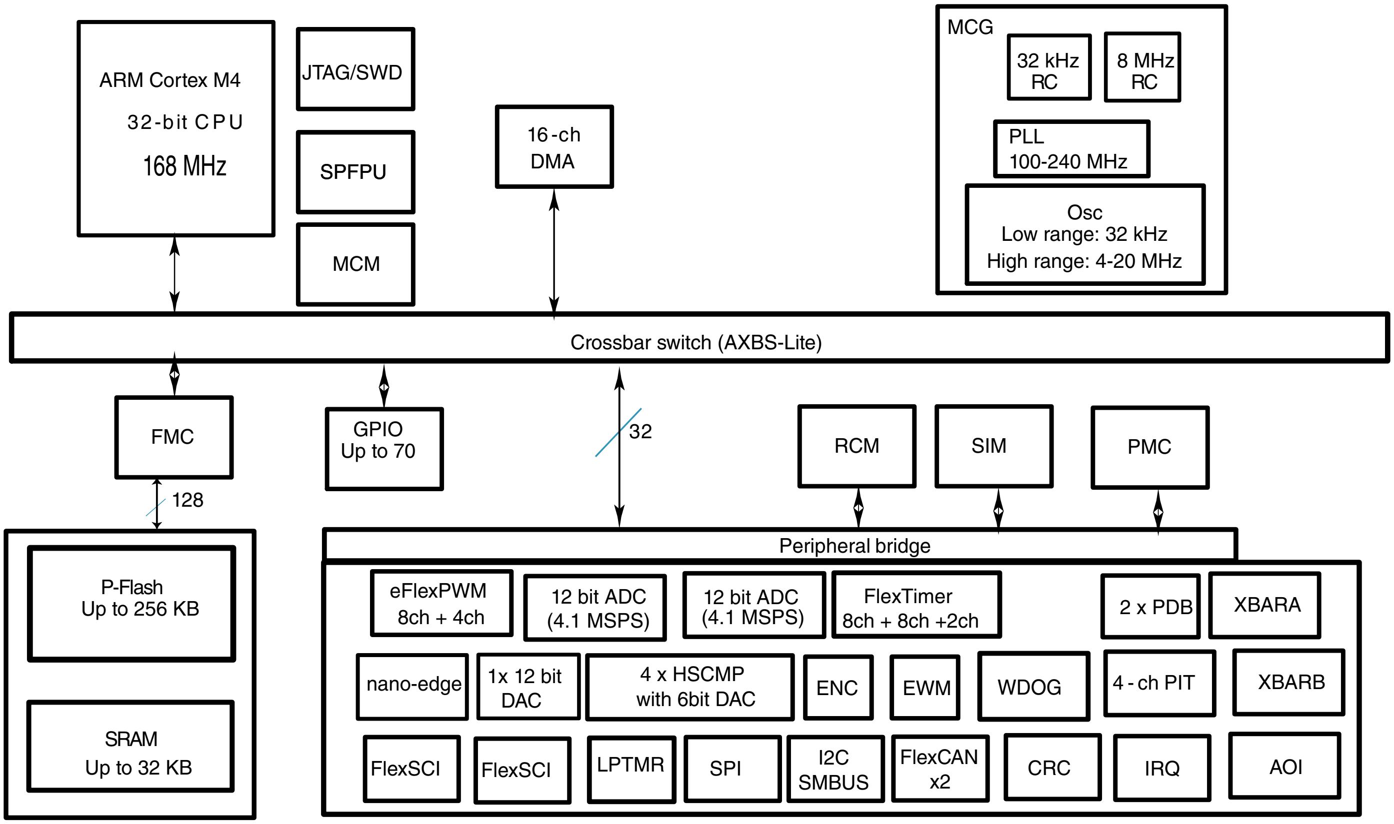


Figure 1. KV4x block diagram

Table 5. Power mode transition operating behaviors

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
t_{POR}	After a POR event, amount of time from the point V_{DD} reaches 1.71 V to execution of the first instruction across the operating temperature range of the chip.	—	—	300	μs	
	• VLLS0 → RUN	—	—	173	μs	
	• VLLS1 → RUN	—	—	172	μs	
	• VLLS2 → RUN	—	—	96	μs	
	• VLLS3 → RUN	—	—	96	μs	
	• VLPS → RUN	—	—	5.4	μs	
	• STOP → RUN	—	—	5.4	μs	

2.2.5 Power consumption operating behaviors

NOTE

The maximum values represent characterized results equivalent to the mean plus three times the standard deviation (mean+3σ)

Table 6. Power consumption operating behaviors (All IDDs are Target values)

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
I_{DD_RUN}	Run mode current — all peripheral clocks disabled, code executing from flash, excludes IDDA • @ 1.8V • @ 3.0V	— —	6.8 6.9	17.2 17.4	mA mA	Core frequency of 25 MHz.
I_{DD_RUN}	Run mode current — all peripheral clocks disabled, code executing from flash, excludes IDDA • @ 1.8V • @ 3.0V	—	9.9	19.7	mA	Core frequency of 50 MHz.

Table continues on the next page...

Table 6. Power consumption operating behaviors (All IDDs are Target values) (continued)

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
	• @ –40 to 25°C	—	2.7	3.3	μA	
	• @ 70°C	—	6.6	12.2	μA	
	• @ 105°C	—	25.9	50.5	μA	
I_{DD_VLLS1}	Very low-leakage stop mode 1 current at 3.0 V					
	• @ –40 to 25°C	—	740	1200	nA	
	• @ 70°C	—	2.5	10.6	μA	
	• @ 105°C	—	11.1	26.5	μA	
I_{DD_VLLS0B}	Very low-leakage stop mode 0 current at 3.0 V with POR detect circuit enabled					
	• @ –40 to 25°C	—	420	832	nA	
	• @ 70°C	—	1.9	9.4	μA	
	• @ 105°C	—	10.8	26.3	μA	
I_{DD_VLLS0A}	Very low-leakage stop mode 0 current at 3.0 V with POR detect circuit disabled					
	• @ –40 to 25°C	—	200	599	nA	
	• @ 70°C	—	1.8	10.5	μA	
	• @ 105°C	—	10.8	26.3	μA	

Table 7. Low power mode peripheral adders — typical value

Symbol	Description	Temperature (°C)						Unit
		-40	25	50	70	85	105	
$I_{IREFSTEN4MHz}$	4 MHz internal reference clock (IRC) adder. Measured by entering STOP or VLPS mode with 4 MHz IRC enabled.	56	56	56	56	56	56	μA
$I_{IREFSTEN32KHz}$	32 kHz internal reference clock (IRC) adder. Measured by entering STOP mode with the 32 kHz IRC enabled.	52	52	52	52	52	52	μA
$I_{EREFSTEN4MHz}$	External 4 MHz crystal clock adder. Measured by entering STOP or VLPS mode with the crystal enabled.	206	228	237	245	251	258	uA
$I_{EREFSTEN32KHz}$	External 32 kHz crystal clock adder by means of the OSC0_CR[EREFSTEN and EREFSTEN] bits. Measured by entering all modes with the crystal enabled.							nA
	VLLS1							
	VLLS3	440	490	540	560	570	580	
	VLPS	440	490	540	560	570	580	
	STOP	510	560	560	560	610	680	

Table continues on the next page...

1. Determined according to IEC Standard 61967-1, *Integrated Circuits - Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 1: General Conditions and Definitions* and IEC Standard 61967-2, *Integrated Circuits - Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 2: Measurement of Radiated Emissions—TEM Cell and Wideband TEM Cell Method*. Measurements were made while the microcontroller was running basic application code. The reported emission level is the value of the maximum measured emission, rounded up to the next whole number, from among the measured orientations in each frequency range.
2. V_{DD} = 3.3 V, T_A = 25 °C, f_{OSC} = 10 MHz (crystal), f_{SYS} = 75 MHz, f_{BUS} = 25 MHz
3. Specified according to Annex D of IEC Standard 61967-2, *Measurement of Radiated Emissions—TEM Cell and Wideband TEM Cell Method*

2.2.7 Designing with radiated emissions in mind

To find application notes that provide guidance on designing your system to minimize interference from radiated emissions:

1. Go to www.nxp.com.
2. Perform a keyword search for "EMC design."

2.2.8 Capacitance attributes

Table 9. Capacitance attributes

Symbol	Description	Min.	Max.	Unit
C_{IN_A}	Input capacitance: analog pins	—	7	pF
C_{IN_D}	Input capacitance: digital pins	—	7	pF

2.3 Switching specifications

2.3.1 Typical device clock specifications

Table 10. Typical device clock specifications

Symbol	Description	Min.	Max.	Unit	Notes
High Speed RUN mode					
f_{SYS}	System and core clock	—	168	MHz	
f_{BUS}	Bus and Flash clock	—	24	MHz	
f_{FPCK}	Fast peripheral clock	—	84	MHz	
f_{NANO}	Nano-edge clock	—	168	MHz	
Normal run mode					
f_{SYS}	System and core clock	—	100	MHz	
f_{BUS}	Bus and Flash clock	—	25	MHz	

Table continues on the next page...

Table 10. Typical device clock specifications (continued)

Symbol	Description	Min.	Max.	Unit	Notes
f_{FPCK}	Fast peripheral clock	—	100	MHz	
f_{NANO}	Nano-edge clock	—	200	MHz	
Low Speed RUN mode					
f_{SYS}	System and core clock	—	50	MHz	
f_{BUS}	Bus and Flash clock	—	25	MHz	
f_{FPCK}	Fast peripheral clock	—	100	MHz	
f_{NANO}	Nano-edge clock	—	200	MHz	

NOTE

When NaneEdge circuit is enabled, the following clock set must be followed:

1. NanoEdge clock source must be from the PLL output
2. NanoEdge clock must be 2x the fast peripheral clock
3. NanoEdge clock must in the range of 164 Mhz ~232 Mhz

2.3.2 General switching specifications

These general purpose specifications apply to all signals configured for GPIO, UART, and I^2C signals.

Table 11. General switching specifications

Symbol	Description	Min.	Max.	Unit	Notes
	GPIO pin interrupt pulse width (digital glitch filter disabled) — Synchronous path	1.5	—	Bus clock cycles	1
	External RESET and NMI pin interrupt pulse width — Asynchronous path	100	—	ns	2
	GPIO pin interrupt pulse width — Asynchronous path	16	—	ns	2
	Port rise and fall time Fast slew rate 1.71≤ VDD ≤ 2.7 V 2.7 ≤ VDD ≤ 3.6 V	 — —	 8 7	 ns ns	3
	Port rise and fall time Slow slew rate 1.71≤ VDD ≤ 2.7 V 2.7 ≤ VDD ≤ 3.6 V	 — —	 25 15	 ns ns	

Table 16. JTAG limited voltage range electricals (continued)

Symbol	Description	Min.	Max.	Unit
J11	TCLK low to TDO data valid	—	19	ns
J12	TCLK low to TDO high-Z	—	17	ns
J13	$\overline{TRST}$ assert time	100	—	ns
J14	$\overline{TRST}$ setup time (negation) to TCLK high	8	—	ns

Table 17. JTAG full voltage range electricals

Symbol	Description	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
J1	TCLK frequency of operation • Boundary Scan • JTAG and CJTAG • Serial Wire Debug	 0 0 0	 10 20 40	MHz
J2	TCLK cycle period	1/J1	—	ns
J3	TCLK clock pulse width • Boundary Scan • JTAG and CJTAG • Serial Wire Debug	 50 25 12.5	 — — —	 ns ns ns
J4	TCLK rise and fall times	—	3	ns
J5	Boundary scan input data setup time to TCLK rise	20	—	ns
J6	Boundary scan input data hold time after TCLK rise	2.0	—	ns
J7	TCLK low to boundary scan output data valid	—	30.6	ns
J8	TCLK low to boundary scan output high-Z	—	25	ns
J9	TMS, TDI input data setup time to TCLK rise	8	—	ns
J10	TMS, TDI input data hold time after TCLK rise	1.0	—	ns
J11	TCLK low to TDO data valid	—	19.0	ns
J12	TCLK low to TDO high-Z	—	17.0	ns
J13	$\overline{TRST}$ assert time	100	—	ns
J14	$\overline{TRST}$ setup time (negation) to TCLK high	8	—	ns

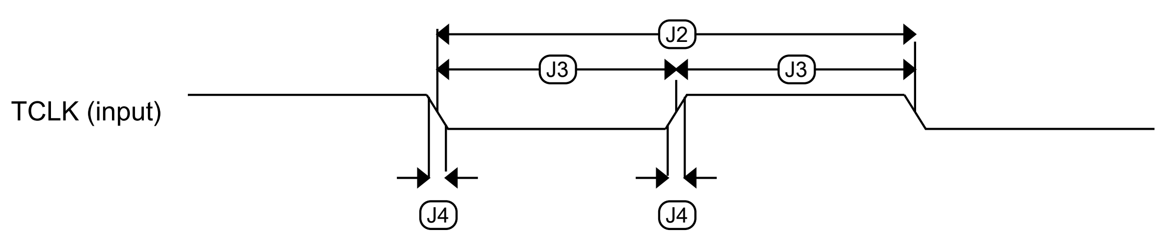


Figure 9. Test clock input timing

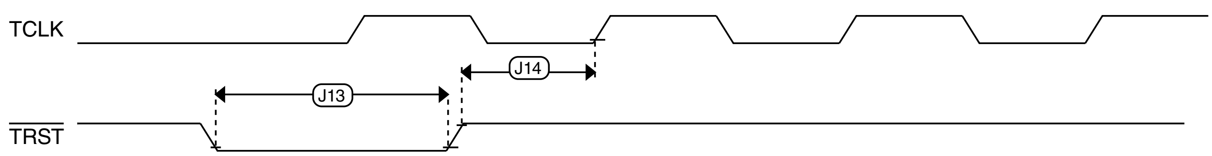


Figure 12. $\overline{TRST}$ timing

3.2 System modules

There are no specifications necessary for the device's system modules.

3.3 Clock modules

3.3.1 MCG specifications

Table 18. MCG specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
f_{ints_ft}	Internal reference frequency (slow clock) — factory trimmed at nominal VDD and 25 °C	—	32.768	—	kHz	
f_{ints_t}	Internal reference frequency (slow clock) — user trimmed	31.25	—	39.0625	kHz	
$\Delta_{fdco\_res\_t}$	Resolution of trimmed average DCO output frequency at fixed voltage and temperature — using SCTRIM and SCFTRIM	—	± 0.3	± 0.6	$\%f_{dco}$	1
$\Delta f_{dco\_res\_t}$	Resolution of trimmed average DCO output frequency at fixed voltage and temperature — using SCTRIM only	—	± 0.2	± 0.5	$\%f_{dco}$	1
Δf_{dco_t}	Total deviation of trimmed average DCO output frequency over voltage and temperature	—	± 0.5	± 2	$\%f_{dco}$	1
Δf_{dco_t}	Total deviation of trimmed average DCO output frequency over fixed voltage and temperature range of 0–70°C	—		± 1	$\%f_{dco}$	1
f_{intf_ft}	Internal reference frequency (fast clock) — factory trimmed at nominal VDD and 25°C	—	4	—	MHz	
f_{intf_t}	Internal reference frequency (fast clock) — user trimmed at nominal VDD and 25 °C	3	—	5	MHz	
f_{loc_low}	Loss of external clock minimum frequency — RANGE = 00	(3/5) x f_{ints_t}	—	—	kHz	

Table continues on the next page...

Table 18. MCG specifications (continued)

Symbol	Description		Min.	Typ.	Max.	Unit	Notes
f_{loc_high}	Loss of external clock minimum frequency — RANGE = 01, 10, or 11		(16/5) x f_{ints_t}	—	—	kHz	
FLL							
f_{fll_ref}	FLL reference frequency range		31.25	—	39.0625	kHz	
f_{dco}	DCO output frequency range	Low range (DRS=00) $640 \times f_{fll\_ref}$	20	20.97	25	MHz	2, 3
		Mid range (DRS=01) $1280 \times f_{fll\_ref}$	40	41.94	50	MHz	
		Mid-high range (DRS=10) $1920 \times f_{fll\_ref}$	60	62.91	75	MHz	
		High range (DRS=11) $2560 \times f_{fll\_ref}$	80	83.89	100	MHz	
$f_{dco\_t\_DMX32}$	DCO output frequency	Low range (DRS=00) $732 \times f_{fll\_ref}$	—	23.99	—	MHz	4, 5
		Mid range (DRS=01) $1464 \times f_{fll\_ref}$	—	47.97	—	MHz	
		Mid-high range (DRS=10) $2197 \times f_{fll\_ref}$	—	71.99	—	MHz	
		High range (DRS=11) $2929 \times f_{fll\_ref}$	—	95.98	—	MHz	
J_{cyc_fll}	FLL period jitter • f_{DCO} = 48 MHz • f_{DCO} = 98 MHz		— —	180 150	— —	ps	
$t_{fll\_acquire}$	FLL target frequency acquisition time		—	—	1	ms	6
PLL							
f_{pll_ref}	PLL reference frequency range		8	—	16	MHz	
f_{vcoclk_2x}	VCO output frequency		220	—	480	MHz	
f_{vcoclk}	PLL output frequency		110	—	240	MHz	
f_{vcoclk_90}	PLL quadrature output frequency		110	—	240	MHz	
I_{pll}	PLL operating current • VCO @ 176 MHz ($f_{osc\_hi\_1}$ = 32 MHz, f_{pll_ref} = 8 MHz, VDIV multiplier = 22)		—	2.8	—	mA	7
I_{pll}	PLL operating current • VCO @ 360 MHz ($f_{osc\_hi\_1}$ = 32 MHz, f_{pll_ref} = 8 MHz, VDIV multiplier = 45)		—	4.7	—	mA	7
J_{cyc_pll}	PLL period jitter (RMS) • f_{vco} = 48 MHz • f_{vco} = 120 MHz		— —	120 75	— —	ps ps	8
J_{acc_pll}	PLL accumulated jitter over 1µs (RMS)						8

Table continues on the next page...

Table 19. Oscillator DC electrical specifications (continued)

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
	• 8 MHz	—	500	—	μA	
	• 16 MHz	—	2.5	—	mA	
	• 24 MHz	—	3	—	mA	
	• 32 MHz	—	4	—	mA	
C_x	EXTAL load capacitance	—	—	—		2, 3
C_y	XTAL load capacitance	—	—	—		2, 3
R_F	Feedback resistor — low-frequency, low-power mode (HGO=0)	—	—	—	MΩ	2, 4
	Feedback resistor — low-frequency, high-gain mode (HGO=1)	—	10	—	MΩ	
	Feedback resistor — high-frequency, low-power mode (HGO=0)	—	—	—	MΩ	
	Feedback resistor — high-frequency, high-gain mode (HGO=1)	—	1	—	MΩ	
R_S	Series resistor — low-frequency, low-power mode (HGO=0)	—	—	—	kΩ	
	Series resistor — low-frequency, high-gain mode (HGO=1)	—	200	—	kΩ	
	Series resistor — high-frequency, low-power mode (HGO=0)	—	—	—	kΩ	
	Series resistor — high-frequency, high-gain mode (HGO=1)	—	0	—	kΩ	
V_{pp}[5]	Peak-to-peak amplitude of oscillation (oscillator mode) — low-frequency, low-power mode (HGO=0)	—	0.6	—	V	
	Peak-to-peak amplitude of oscillation (oscillator mode) — low-frequency, high-gain mode (HGO=1)	—	V_{DD}	—	V	
	Peak-to-peak amplitude of oscillation (oscillator mode) — high-frequency, low-power mode (HGO=0)	—	0.6	—	V	
	Peak-to-peak amplitude of oscillation (oscillator mode) — high-frequency, high-gain mode (HGO=1)	—	V_{DD}	—	V	

1. V_{DD}=3.3 V, Temperature =25 °C
2. See crystal or resonator manufacturer's recommendation
3. C_x,C_y can be provided by using the integrated capacitors when the low frequency oscillator (RANGE = 00) is used. For all other cases external capacitors must be used.
4. When low power mode is selected, R_F is integrated and must not be attached externally.
5. The EXTAL and XTAL pins should only be connected to required oscillator components and must not be connected to any other devices.

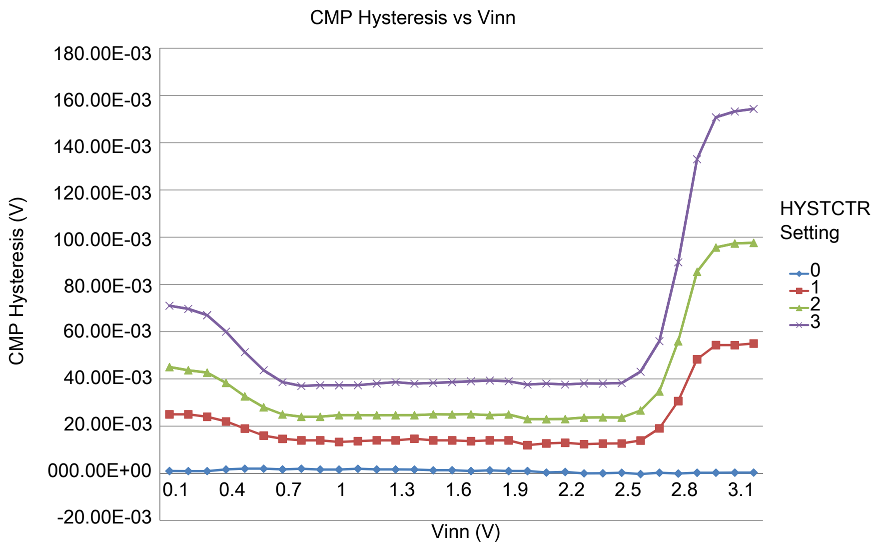


Figure 15. Typical hysteresis vs. Vin level (V_{DD} = 3.3 V, PMODE = 1)

3.6.3 12-bit DAC electrical characteristics

3.6.3.1 12-bit DAC operating requirements

Table 27. 12-bit DAC operating requirements

Symbol	Desciption	Min.	Max.	Unit	Notes
V_{DDA}	Supply voltage	1.71	3.6	V	
V_{DACR}	Reference voltage	1.13	3.6	V	1
C_L	Output load capacitance	—	100	pF	2
I_L	Output load current	—	1	mA	

1. The DAC reference can be selected to be V_{DDA} or V_{REFH}.
2. A small load capacitance (47 pF) can improve the bandwidth performance of the DAC.

3.6.3.2 12-bit DAC operating behaviors

Table 28. 12-bit DAC operating behaviors

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
I_{DDA_DACLP}	Supply current — low-power mode	—	—	330	μA	
I_{DDA_DACHP}	Supply current — high-speed mode	—	—	1200	μA	
t_{DACLP}	Full-scale settling time (0x080 to 0xF7F) — low-power mode	—	100	200	μs	1

Table continues on the next page...

Table 33. Master mode DSPI timing for open drain pads (limited voltage range) (continued)

Num	Description	Min.	Max.	Unit	Notes
	Frequency of operation	—	25	MHz	
DS1	DSPI_SCK output cycle time	2 x t_{BUS}	—	ns	
DS2	DSPI_SCK output high/low time	$(t_{SCK}/2) - 2$	$(t_{SCK}/2) + 2$	ns	
DS3	DSPI_PCS*n* to DSPI_SCK output valid	$(t_{BUS} \times 2) - 2$	—	ns	1
DS4	DSPI_SCK to DSPI_PCS*n* output hold	$(t_{BUS} \times 2) - 2$	—	ns	2
DS5	DSPI_SCK to DSPI_SOUT valid	—	15.5	ns	
DS6	DSPI_SCK to DSPI_SOUT invalid	–3	—	ns	
DS7	DSPI_SIN to DSPI_SCK input setup	17	—	ns	
DS8	DSPI_SCK to DSPI_SIN input hold	0	—	ns	

1. The delay is programmable in SPIx_CTARn[PSSCK] and SPIx_CTARn[CSSCK].
2. The delay is programmable in SPIx_CTARn[PASC] and SPIx_CTARn[ASC].

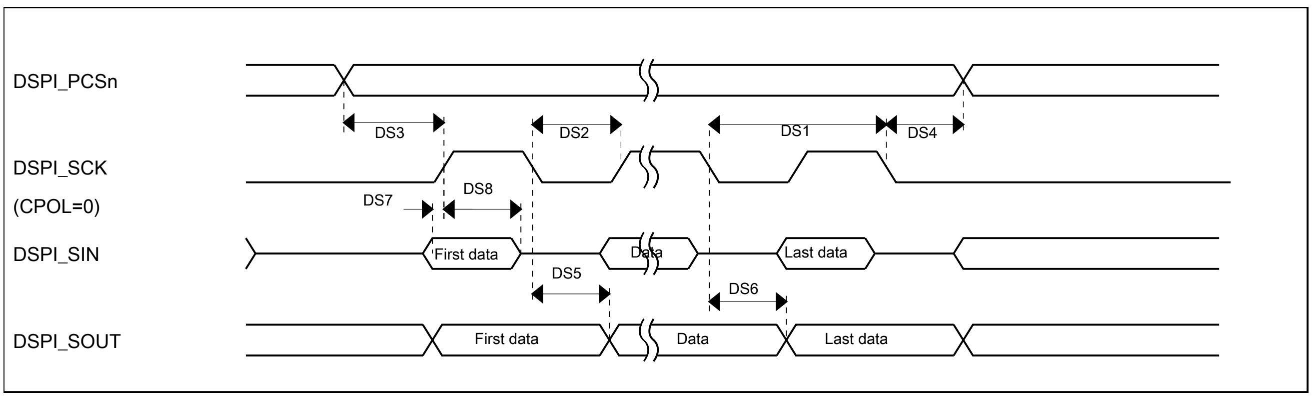


Figure 18. DSPI classic SPI timing — master mode

Table 34. Slave mode DSPI timing for normal pads (limited voltage range)

Num	Description	Min.	Max.	Unit
	Operating voltage	2.7	3.6	V
	Frequency of operation		12.5	MHz
DS9	DSPI_SCK input cycle time	4 x t_{BUS}	—	ns
DS10	DSPI_SCK input high/low time	$(t_{SCK}/2) - 2$	$(t_{SCK}/2) + 2$	ns
DS11	DSPI_SCK to DSPI_SOUT valid	—	21	ns
DS12	DSPI_SCK to DSPI_SOUT invalid	0	—	ns
DS13	DSPI_SIN to DSPI_SCK input setup	2	—	ns
DS14	DSPI_SCK to DSPI_SIN input hold	7	—	ns
DS15	$\overline{\text{DSPI\_SS}}$ active to DSPI_SOUT driven	—	15	ns
DS16	$\overline{\text{DSPI\_SS}}$ inactive to DSPI_SOUT not driven	—	15	ns

Table 35. Slave mode DSPI timing for fast pads (limited voltage range)

Num	Description	Min.	Max.	Unit
	Operating voltage	2.7	3.6	V
	Frequency of operation		25	MHz
DS9	DSPI_SCK input cycle time	4 x t_{BUS}	—	ns
DS10	DSPI_SCK input high/low time	$(t_{SCK}/2) - 2$	$(t_{SCK}/2) + 2$	ns
DS11	DSPI_SCK to DSPI_SOUT valid	—	17	ns
DS12	DSPI_SCK to DSPI_SOUT invalid	0	—	ns
DS13	DSPI_SIN to DSPI_SCK input setup	2	—	ns
DS14	DSPI_SCK to DSPI_SIN input hold	7	—	ns
DS15	$\overline{\text{DSPI\_SS}}$ active to DSPI_SOUT driven	—	11	ns
DS16	$\overline{\text{DSPI\_SS}}$ inactive to DSPI_SOUT not driven	—	11	ns

Table 36. Slave mode DSPI timing for open drain pads (limited voltage range)

Num	Description	Min.	Max.	Unit
	Operating voltage	2.7	3.6	V
	Frequency of operation		12.5	MHz
DS9	DSPI_SCK input cycle time	4 x t_{BUS}	—	ns
DS10	DSPI_SCK input high/low time	$(t_{SCK}/2) - 2$	$(t_{SCK}/2) + 2$	ns
DS11	DSPI_SCK to DSPI_SOUT valid	—	28	ns
DS12	DSPI_SCK to DSPI_SOUT invalid	0	—	ns
DS13	DSPI_SIN to DSPI_SCK input setup	2	—	ns
DS14	DSPI_SCK to DSPI_SIN input hold	7	—	ns
DS15	$\overline{\text{DSPI\_SS}}$ active to DSPI_SOUT driven	—	22	ns
DS16	$\overline{\text{DSPI\_SS}}$ inactive to DSPI_SOUT not driven	—	22	ns

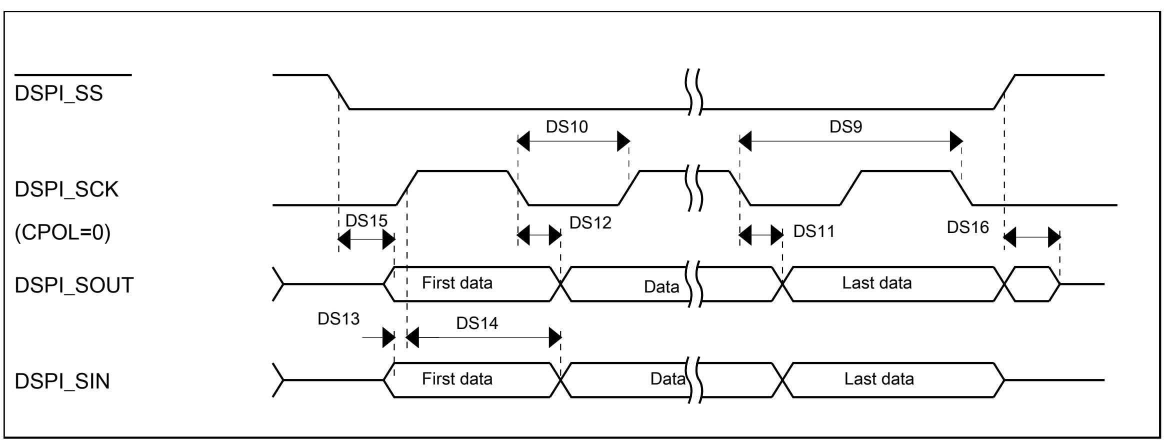


Figure 19. DSPI classic SPI timing — slave mode

3.9.2 SPI (DSPI) switching specifications (full voltage range)

The DMA Serial Peripheral Interface (DSPI) provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The tables below provides DSPI timing characteristics for classic SPI timing modes. Refer to the DSPI chapter of the Reference Manual for information on the modified transfer formats used for communicating with slower peripheral devices.

NOTE

Fast pads:

- SIN: PTE19
- SOUT: PTE18
- SCK: PTE17
- PCS: PTE16

Open drain pads:

- SIN: PTC7
- SOUT: PTC6

Table 37. Master mode DSPI timing for normal pads (full voltage range)

Num	Description	Min.	Max.	Unit	Notes
	Operating voltage	1.71	3.6	V	1
	Frequency of operation	—	18.75	MHz	
DS1	DSPI_SCK output cycle time	4 x t_{BUS}	—	ns	
DS2	DSPI_SCK output high/low time	(t_{SCK}/2) - 4	($t_{SCK/2)}$ + 4	ns	
DS3	DSPI_PCS*n* valid to DSPI_SCK delay	(t_{BUS} x 2) − 4	—	ns	2
DS4	DSPI_SCK to DSPI_PCS*n* invalid delay	(t_{BUS} x 2) − 4	—	ns	3
DS5	DSPI_SCK to DSPI_SOUT valid	—	10	ns	
DS6	DSPI_SCK to DSPI_SOUT invalid	-7.8	—	ns	
DS7	DSPI_SIN to DSPI_SCK input setup	24	—	ns	
DS8	DSPI_SCK to DSPI_SIN input hold	0	—	ns	

1. The DSPI module can operate across the entire operating voltage for the processor, but to run across the full voltage range the maximum frequency of operation is reduced.
2. The delay is programmable in SPIx_CTARn[PSSCK] and SPIx_CTARn[CSSCK].
3. The delay is programmable in SPIx_CTARn[PASC] and SPIx_CTARn[ASC].

Table 42. Slave mode DSPI timing for open drain pads (full voltage range)

Num	Description	Min.	Max.	Unit
	Operating voltage	1.71	3.6	V
	Frequency of operation	—	9.375	MHz
DS9	DSPI_SCK input cycle time	8 x t_{BUS}	—	ns
DS10	DSPI_SCK input high/low time	$(t_{SCK}/2)$ - 4	$(t_{SCK/2})$ + 4	ns
DS11	DSPI_SCK to DSPI_SOUT valid	—	43.5	ns
DS12	DSPI_SCK to DSPI_SOUT invalid	0	—	ns
DS13	DSPI_SIN to DSPI_SCK input setup	2.5	—	ns
DS14	DSPI_SCK to DSPI_SIN input hold	7	—	ns
DS15	$\overline{\text{DSPI\_SS}}$ active to DSPI_SOUT driven	—	38	ns
DS16	$\overline{\text{DSPI\_SS}}$ inactive to DSPI_SOUT not driven	—	38	ns

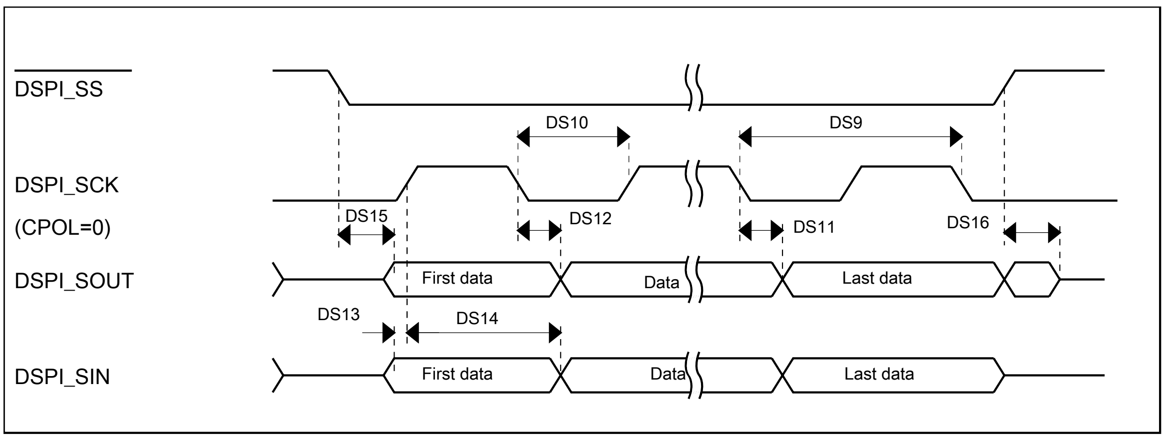


Figure 21. DSPI classic SPI timing — slave mode

3.9.3 I²C

See General switching specifications.

3.9.4 UART

See General switching specifications.

3.10 Kinetis Motor Suite (KMS)

Kinetis Motor Suite is a bundled software solution that enables the rapid configuration of motor drive systems, and accelerates development of the final motor drive application.

Several members of the KV4x family are enabled with Kinetis Motor Suite. The enabled devices can be identified within the orderable part numbers in KMS Orderable part numbers summary . For more information,see Kinetis Motor Suite User's Guide (KMS100UG) and Kinetis Motor Suite API Reference Manual (KMS100RM).

NOTE

To find the associated resource, go to http://www.nxp.com and perform a search using the Document ID.

4 Dimensions

4.1 Obtaining package dimensions

Package dimensions are provided in package drawings.

To find a package drawing, go to www.nxp.com and perform a keyword search for the drawing's document number:

If you want the drawing for this package	Then use this document number
48-pin LQFP	98ASH00962A
64-pin LQFP	98ASS23234W
100-pin LQFP	98ASS23308W

5 Pinout

5.1 KV4x Signal Multiplexing and Pin Assignments

The following table shows the signals available on each pin and the locations of these pins on the devices supported by this document. The Port Control Module is responsible for selecting which ALT functionality is available on each pin.

100 LQFP	64 LQFP	48 LQFP	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7
30	—	—	VDD	VDD	VDD							
31	20	15	PTE24	ADCB_CH4	ADCB_CH4	PTE24	CAN1_TX	FTM0_CH0	XBAR0_IN2	I2C0_SCL	EWM_OUT_b	XBAR0_ OUT4
32	21	16	PTE25/ LLWU_P21	ADCB_CH5	ADCB_CH5	PTE25/ LLWU_P21	CAN1_RX	FTM0_CH1	XBAR0_IN3	I2C0_SDA	EWM_IN	XBAR0_ OUT5
33	—	—	PTE26	DISABLED		PTE26						
34	22	17	PTA0	JTAG_TCLK/ SWD_CLK		PTA0	UART0_ CTS_b/ UART0_ COL_b	FTM0_CH5	XBAR0_IN4	EWM_IN		JTAG_TCLK/ SWD_CLK
35	23	18	PTA1	JTAG_TDI		PTA1	UART0_RX	FTM0_CH6	CMP0_OUT		FTM1_CH1	JTAG_TDI
36	24	19	PTA2	JTAG_TDO/ TRACE_ SWO		PTA2	UART0_TX	FTM0_CH7	CMP1_OUT		FTM1_CH0	JTAG_TDO/ TRACE_ SWO
37	25	20	PTA3	JTAG_TMS/ SWD_DIO		PTA3	UART0_ RTS_b	FTM0_CH0	XBAR0_IN9	EWM_OUT_b	FLEXPWMA_ A0	JTAG_TMS/ SWD_DIO
38	26	21	PTA4/ LLWU_P3	NMI_b		PTA4/ LLWU_P3		FTM0_CH1	XBAR0_IN10	FTM0_FLT3	FLEXPWMA_ B0	NMI_b
39	27	—	PTA5	DISABLED		PTA5		FTM0_CH2		CMP2_OUT		JTAG_TRST_ b
40	—	22	VDD	VDD	VDD							
41	—	23	VSS	VSS	VSS							
42	28	—	PTA12	CMP2_IN0	CMP2_IN0	PTA12	CAN0_TX	FTM1_CH0				FTM1_QD_ PHA
43	29	—	PTA13/ LLWU_P4	CMP2_IN1	CMP2_IN1	PTA13/ LLWU_P4	CAN0_RX	FTM1_CH1				FTM1_QD_ PHB
44	—	—	PTA14	CMP3_IN0	CMP3_IN0	PTA14	SPI0_PCS0	UART0_TX				
45	—	—	PTA15	CMP3_IN1	CMP3_IN1	PTA15	SPI0_SCK	UART0_RX				
46	—	—	PTA16	CMP3_IN2	CMP3_IN2	PTA16	SPI0_SOUT	UART0_ CTS_b/ UART0_ COL_b				
47	—	—	PTA17	ADCA_CH7e	ADCA_CH7e	PTA17	SPI0_SIN	UART0_ RTS_b				
48	30	—	VDD	VDD	VDD							
49	31	—	VSS	VSS	VSS							
50	32	24	PTA18	EXTAL0	EXTAL0	PTA18	XBAR0_IN7	FTM0_FLT2	FTM_CLKIN0	XBAR0_ OUT8	FTM3_CH2	
51	33	25	PTA19	XTAL0	XTAL0	PTA19	XBAR0_IN8	FTM1_FLT0	FTM_CLKIN1	XBAR0_ OUT9	LPTMR0_ ALT1	
52	34	26	RESET_b	RESET_b	RESET_b							
53	35	27	PTB0/ LLWU_P5	ADCB_CH2	ADCB_CH2	PTB0/ LLWU_P5	I2C0_SCL	FTM1_CH0			FTM1_QD_ PHA	UART0_RX
54	36	28	PTB1	ADCB_CH3	ADCB_CH3	PTB1	I2C0_SDA	FTM1_CH1	FTM0_FLT2	EWM_IN	FTM1_QD_ PHB	UART0_TX

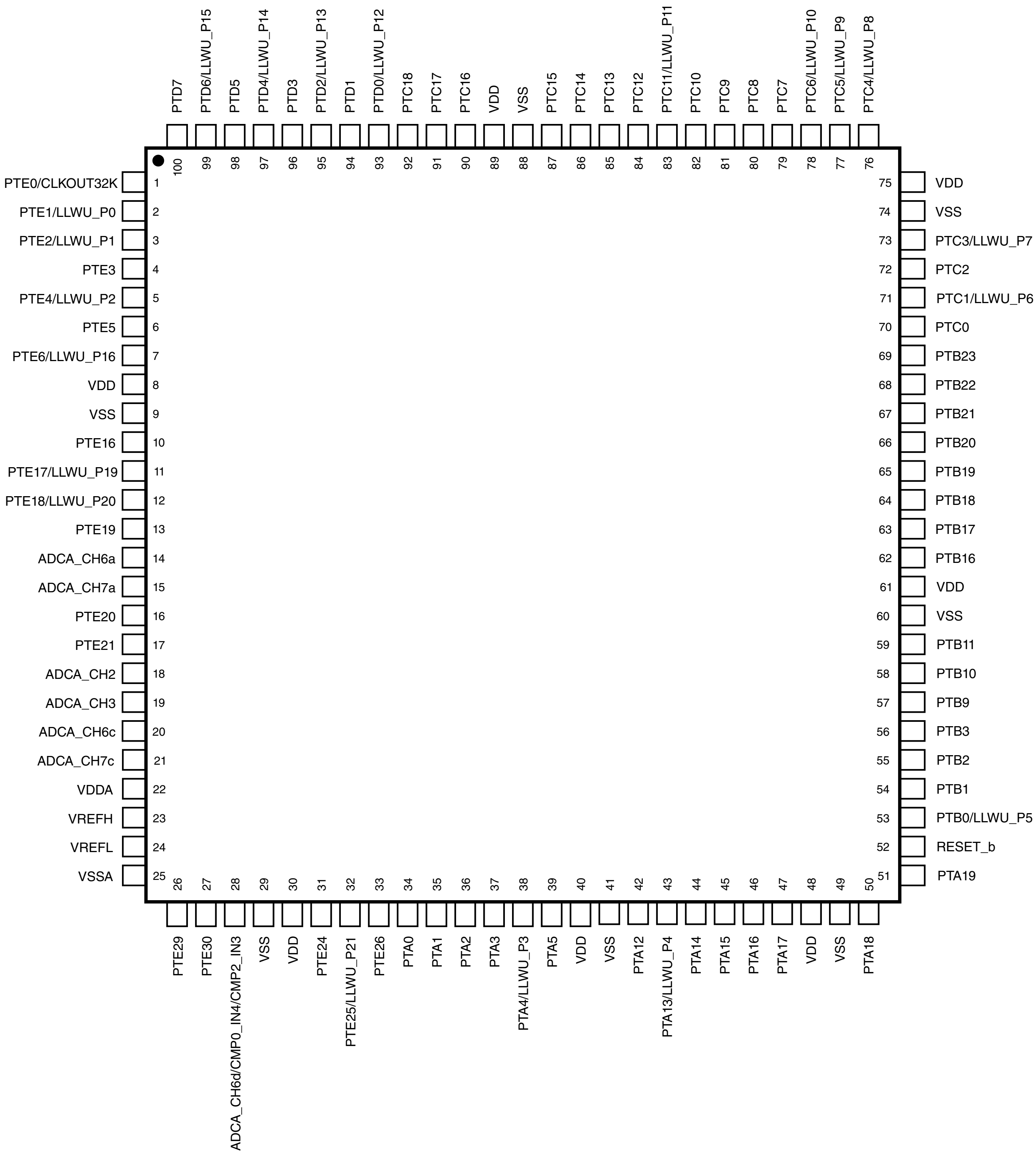


Figure 22. 100-pin LQFP

6.1 Determining valid orderable parts

Valid orderable part numbers are provided on the web. To determine the orderable part numbers for this device, go to www.nxp.com and perform a part number search for the MKV4x device numbers.

7 Part identification

7.1 Description

Part numbers for the chip have fields that identify the specific part. You can use the values of these fields to determine the specific part you have received.

7.2 Format

Part numbers for this device have the following format:

Q KV## A FFF T PP CC S N

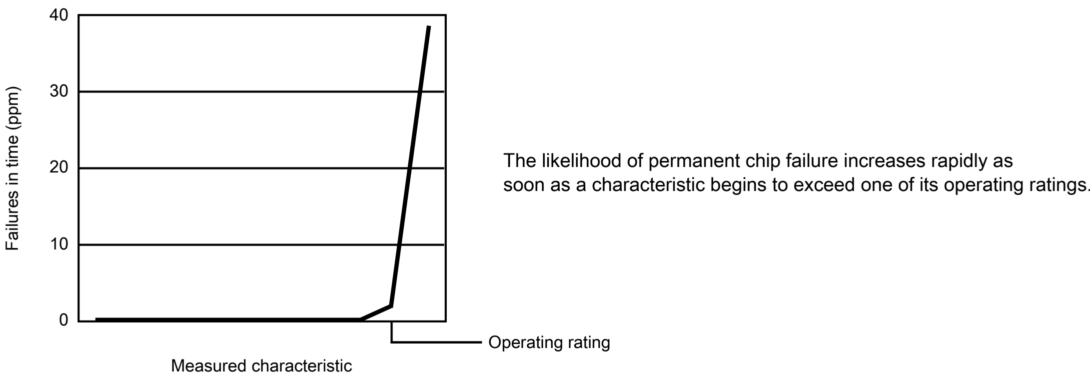
7.3 Fields

This table lists the possible values for each field in the part number (not all combinations are valid):

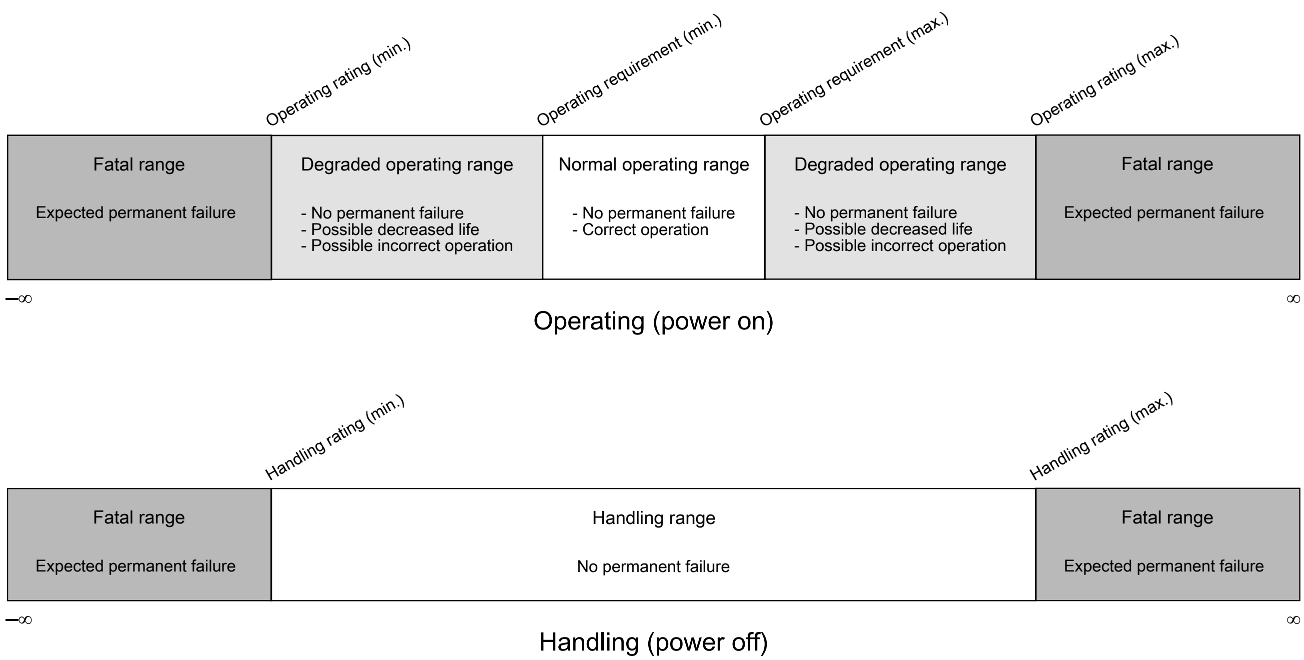
Field	Description	Values
Q	Qualification status	• M = Fully qualified, general market flow • P = Prequalification
KV##	Kinetis family	• KV42 • KV44 • KV46
A	Key attribute	• F = Cortex-M4 w/ DSP and FPU
FFF	Program flash memory size	• 64 = 64 KB • 128 = 128 KB • 256 = 256 KB
T	Temperature range (°C)	• V = –40 to 105
PP	Package identifier	• LF = 48 LQFP (7 mm x 7 mm) • LH = 64 LQFP (10 mm x 10 mm) • LL = 100 LQFP (14 mm x 14 mm)
CC	Maximum CPU frequency (MHz)	• 16 = 168 MHz

Table continues on the next page...

8.5 Result of exceeding a rating



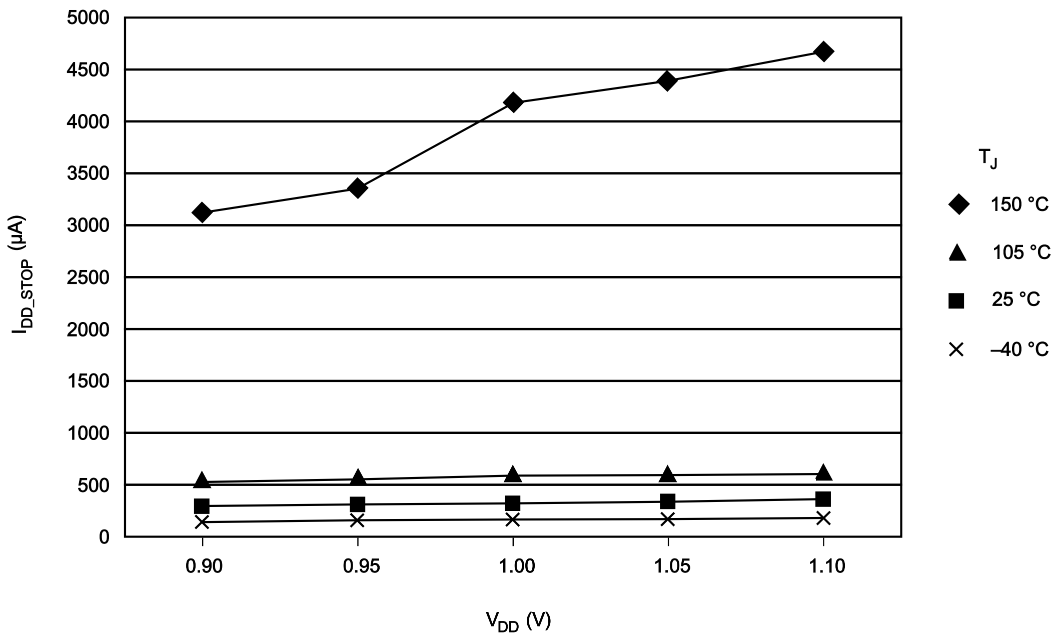
8.6 Relationship between ratings and operating requirements



8.7 Guidelines for ratings and operating requirements

Follow these guidelines for ratings and operating requirements:

- Never exceed any of the chip's ratings.



8.9 Typical Value Conditions

Typical values assume you meet the following conditions (or other conditions as specified):

Symbol	Description	Value	Unit
T_A	Ambient temperature	25	°C
V_{DD}	3.3 V supply voltage	3.3	V

9 Revision history

The following table provides a revision history for this document.

Table 43. Revision history

Rev. No.	Date	Substantial Changes
0	7/2014	Initial NDA release.

1	2/2015	• Added information about 48 LQFP package in the following sections:
		  • Ordering information
		  • Fields

Table continues on the next page...